

μA723QB Precision Voltage Regulator

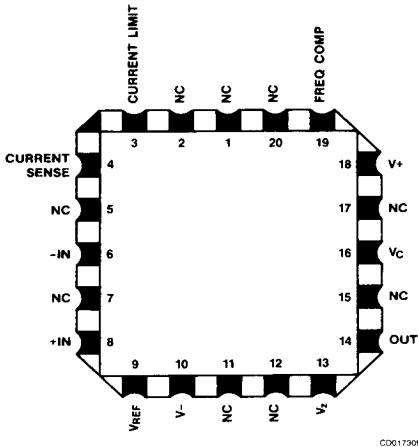
Aerospace and Defense Data Sheet
Linear Products

Description

The μA723QB is a monolithic voltage regulator constructed using the Fairchild Planar Epitaxial process. The device consists of a temperature compensated reference amplifier, error amplifier, power series pass transistor and current-limit circuitry. Additional NPN or PNP pass elements may be used when output currents exceeding 150 mA are required. Provisions are made for adjustable current limiting and remote shutdown. In addition to the above, the device features low standby current drain, low temperature drift and high ripple rejection. The μA723QB is intended for use with positive or negative supplies as a series, shunt, switching, or floating regulator. Applications include laboratory power supplies, isolation regulators for low level data amplifiers, logic card regulators, small instrument power supplies, airborne systems, and other power supplies for digital and linear circuits.⁶

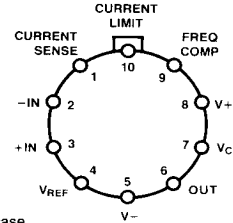
- Positive Or Negative Supply Operation
- Series, Shunt, Switching, Or Floating Operation
- Low Line And Load Regulation
- Output Voltage Adjustable From 2 V To 37 V
- Output Current To 150 mA Without External Pass Transistor

Connection Diagram 20-Terminal CCP (Top View)



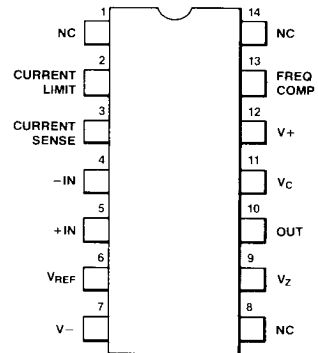
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Connection Diagram 10-Lead Can (Top View)



Lead 5 connected to case.

Connection Diagram 14-Lead DIP (Top View)



Order Information

Part No.	Case/ Finish	Package Code
μA723DMQB	CA	D-1 14-Lead DIP
μA723HMQB	IC	A-2 10-Lead Can
μA723LMQB	2C	C-2 20-Terminal CCP

JAN Product Available

10201	BCA	D-1 14-Lead DIP
10201	BCB	D-1 14-Lead DIP
10201	B/A	A-2 10-Lead Can
10201	B/C	A-2 10-Lead Can

Absolute Maximum Ratings

Storage Temperature Range	-65°C to +175°C
Operating Temperature Range	-55°C to +125°C
Lead Temperature (soldering, 60 s)	300°C
Internal Power Dissipation ⁸	
Can	350 mW
DIP and CCP	400 mW
Pulse Voltage from V+ to V-, (50 ms)	50 V
Continuous Voltage from V+ to V-	40 V
Input/Cutput Voltage Differential	40 V
Differential Input Voltage	± 5 V
Voltage Between Non-Inverting	
Input and V-	8 V
Current from Vz	25 mA
Current from VREF	15 mA

Processing: MIL-STD-883, Method 5004

Burn-In: Method 1015, Condition A, PDA calculated using Method 5005, Subgroup 1

Quality Conformance Inspection: MIL-STD-883, Method 5005

Group A Electrical Tests Subgroups:

1. Static tests at 25°C
2. Static tests at 125°C
3. Static tests at -55°C
4. Dynamic tests at 25°C

Group C and D Endpoints: Group A, Subgroup 1

Notes

1. 100% Test and Group A
2. Group A
3. Periodic tests, Group C
4. Guaranteed but not tested
5. When changes occur, FSC will make data sheet revisions available. Contact local sales representative for the latest revision.
6. For more information on device function, refer to the Fairchild Linear Data Book Commercial Section.
7. The line and load regulation specifications are given for the condition of constant chip temperature. Temperature drift effects must be taken into account separately for high dissipation conditions.
8. Rating applies to ambient temperatures up to 125°C. Above 125°C ambient, rate linearly at 140°C/W for the Can and 120°C/W for the DIP and CCP.

μA723QB

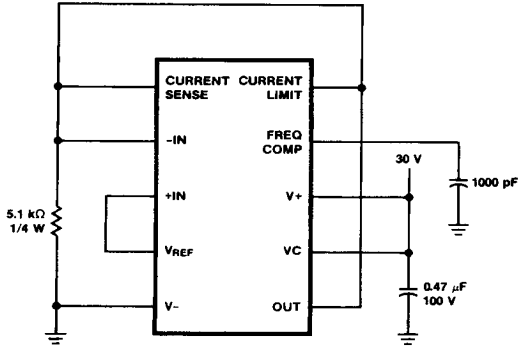
μA723QB

Electrical Characteristics $V_I = V_+ = V_C \leq 12 \text{ V}$, $V_- = 0 \text{ V}$, $V_O = 5.0 \text{ V}$, $I_L = 1.0 \text{ mA}$, $R_{SC} = 0 \ \Omega$, $C_1 = 100 \ \mu\text{F}$, $C_{REF} = 0 \ \mu\text{F}$, unless otherwise specified.

Symbol	Characteristic	Condition	Min	Max	Unit	Note	Subgrp
V_{REF}	Reference Voltage		6.95	7.35	V	1	1,2,3
ΔV_{REF} (LOAD)	Reference Voltage Change With Load	$0 \text{ mA} \leq I_{REF} \leq 5.0 \text{ mA}$		20	mV	1	1
V_{IR}	Input Voltage Range		9.5	40	V	1	1
V_{OR}	Output Voltage Range		2.0	37	V	1	1
$V_I - V_O$	Input/Output Voltage Diff.		3.0	38	V	1	1
V_Z	Zener Voltage	$I_Z = 1.0 \text{ mA}$	5.8	7.2	V	1	1
$V_{R \text{ LINE}}$	Line Regulation ⁷	$12 \text{ V} \leq V_I \leq 15 \text{ V}$		0.1	% V_O	1	1
		$12 \text{ V} \leq V_I \leq 40 \text{ V}$		0.2	% V_O	1	1
		$12 \text{ V} \leq V_I \leq 15 \text{ V}$		0.3	% V_O	1	2,3
$V_{R \text{ LOAD}}$	Load Regulation ⁷	$1.0 \text{ mA} \leq I_L \leq 50 \text{ mA}$		0.15	% V_O	1	1
				0.6	% V_O	1	2,3
$T_C \ V_O$	Average Temp. Coefficient of Output Voltage	$25^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$	-0.010	+0.010	%/ $^\circ\text{C}$	4	2
		$-55^\circ\text{C} \leq T_A \leq 25^\circ\text{C}$	-0.015	+0.015	%/ $^\circ\text{C}$	4	3
I_{SCD}	Standby Current Drain	$V_I = 30 \text{ V}$, $I_L = 0 \text{ mA}$		3.5	mA	1	1
				4.0	mA	4	2
				2.4	mA	4	3
I_{OS}	Output Short Circuit Current	$V_O = 0 \text{ V}$, $R_{SC} = 10 \ \Omega$	45	85	mA	4	1
$\Delta V_I / \Delta V_O$	Ripple Rejection	$f = 10 \text{ kHz}$, $C_{REF} = 0 \ \mu\text{F}$	64		dB	3	4
		$f = 10 \text{ kHz}$, $C_{REF} = 5.0 \ \mu\text{F}$	76		dB	3	4
N_O	Noise	$100 \text{ Hz} \leq f \leq 10 \text{ kHz}$	$C_{REF} = 0 \ \mu\text{F}$	120	μV_{rms}	3	4
			$C_{REF} = 5.0 \ \mu\text{F}$	7.0	μV_{rms}	3	4
$\Delta V_O / \Delta V_I$	Line Transient Response	$\Delta V_I = 3.0 \text{ V}$		10	mV/V	3	4
$\Delta V_O / \Delta I_L$	Load Transient Response	$I_L = 40 \text{ mA}$, $\Delta I_L = 10 \text{ mA}$	-1.5		mV/mA	3	4

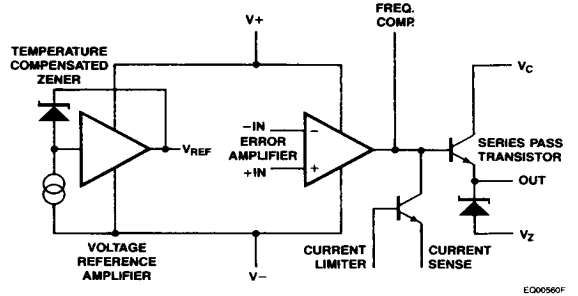
Primary Burn-In Circuit

(38510/10201 may be used by FSC as an alternate)



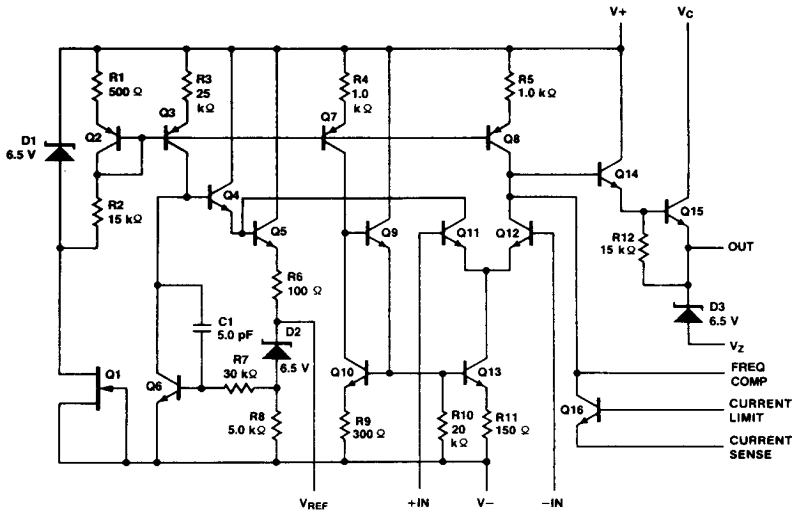
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Block Diagram



EQ00560F

Equivalent Circuit



EQ00570F